SCCS020A - MARCH 1995 - REVISED OCTOBER 2001

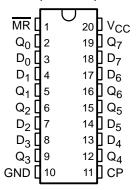
- Function, Pinout, and Drive Compatible With FCT and F Logic
- Reduced V_{OH} (Typically = 3.3 V) Versions of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I_{off} Supports Partial-Power-Down Mode Operation
- Matched Rise and Fall Times
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)
- Fully Compatible With TTL Input and Output Logic Levels
- CY54FCT273T
 - 32-mA Output Sink Current
 - 12-mA Output Source Current
- CY74FCT273T
 - 64-mA Output Sink Current
 - 32-mA Output Source Current

description

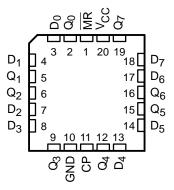
The 'FCT273T devices consist of eight edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common buffered-clock (CP) and master-reset (MR) inputs load and reset all flip-flops simultaneously. These devices are edge-triggered registers. The state of each D input (one setup time before the low-to-high clock transition) is transferred to the corresponding flip-flop's Q output. All outputs are forced low by a low logic level on the MR input.

This device is fully specified for partial-power-down applications using $I_{\rm off}$. The $I_{\rm off}$ circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

CY54FCT273T...D PACKAGE CY74FCT273T...Q OR SO PACKAGE (TOP VIEW)



CY54FCT273T ... L PACKAGE (TOP VIEW)





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ORDERING INFORMATION

TA	PACI	KAGEŤ	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QSOP - Q	Tape and reel	5.8	CY74FCT273CTQCT	FCT273C
	SOIC - SO	Tube	5.8	CY74FCT273CTSOC	FCT273C
	3010 - 30	Tape and reel	5.8	CY74FCT273CTSOCT	FC1273C
	QSOP – Q	Tape and reel	7.2	CY74FCT273ATQCT	FCT273A
–40°C to 85°C	SOIC - SO	Tube		CY74FCT273ATSOC	FCT273A
	3010 = 30	Tape and reel	7.2	CY74FCT273ATSOCT	FC1273A
	QSOP – Q	Tape and reel	13	CY74FCT273TQCT	FCT273
	SOIC - SO	Tube	13	CY74FCT273TSOC	FCT273
	3010 - 30	Tape and reel	13	CY74FCT273TSOCT	FC1273
–55°C to 125°C	LCC – L	Tube	8.3	CY54FCT273ATLMB	

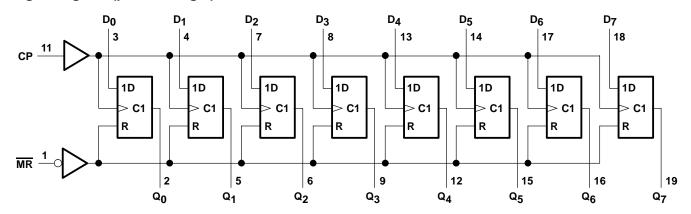
[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

	INPUTS		OUTPUT	OPERATING
MR	CP	D	Q	MODE
L	Х	Χ	L	Reset (clear)
Н	1	h	Н	Load '1'
Н	\uparrow	I	L	Load '0'

 $H=High\,logic\,level\,steady\,state,\,h=High\,logic\,level\,one$ setup time prior to low-to-high clock transition, $L=Low\,logic\,level\,steady\,state,\,l=Low\,logic\,level\,one\,setup\,time$ prior to the low-to-high transition, $X=Don't\,care,\,\uparrow=Low-to-high\,clock\,transition$

logic diagram (positive logic)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range to ground potential	–0.5 V to 7 V
DC input voltage range	–0.5 V to 7 V
DC output voltage range	–0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, θ _{JA} (see Note 1): Q package	68°C/W
SO package	
Ambient temperature range with power applied, T _A	
Storage temperature range, T _{stg}	-65° C to 150° C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions (see Note 2)

		CY	54FCT27	4FCT273T CY74FCT273T			UNIT	
		MIN	NOM	MAX	MIN	NOM	MAX	ONIT
Vcc	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			8.0			0.8	V
ІОН	High-level output current			-12			-32	mA
loL	Low-level output current			32			64	mA
T _A	Operating free-air temperature	-55		125	-40		85	°C

NOTE 2: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.



NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETER		TEST SOMBITIO	NO.	CY	54FCT2	73T	CY	74FCT27	'3T	
PARAMETER		TEST CONDITIO	NS	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNIT
V	V _{CC} = 4.5 V,	$I_{IN} = -18 \text{ mA}$			-0.7	-1.2				٧
VIK	$V_{CC} = 4.75 \text{ V},$	$I_{IN} = -18 \text{ mA}$						-0.7	-1.2	V
	$V_{CC} = 4.5 \text{ V},$	$I_{OH} = -12 \text{ mA}$		2.4	3.3					
Voн	V _{CC} = 4.75 V	$I_{OH} = -32 \text{ mA}$					2			V
	VCC = 4.75 V	$I_{OH} = -15 \text{ mA}$					2.4	3.3		
Voi	$V_{CC} = 4.5 \text{ V},$	$I_{OL} = 32 \text{ mA}$			0.3	0.55				V
VOL	$V_{CC} = 4.75 \text{ V},$	$I_{OL} = 64 \text{ mA}$						0.3	0.55	V
V_{hys}	All inputs				0.2			0.2		V
	$V_{CC} = 5.5 V$,	VIN = VCC				5				μА
ΙΙ	$V_{CC} = 5.25 \text{ V},$	VIN = VCC							5	μΑ
	$V_{CC} = 5.5 \text{ V},$	$V_{1N} = 2.7 \text{ V}$				±1				μА
IH	$V_{CC} = 5.25 \text{ V},$	$V_{1N} = 2.7 \text{ V}$							±1	μΛ
1.,	$V_{CC} = 5.5 \text{ V},$	$V_{IN} = 0.5 V$				±1				μΑ
IIL	$V_{CC} = 5.25 \text{ V},$	$V_{IN} = 0.5 V$							±1	μΛ
l _{off}	$V_{CC} = 0 V$	V _{OUT} = 4.5 V				±1			±1	μΑ
los‡	$V_{CC} = 5.5 \text{ V},$	VOUT = 0 V		-60	-120	-225				mA
ios+	$V_{CC} = 5.25 \text{ V},$	VOUT = 0 V					-60	-120	-225	IIIA
loo	$V_{CC} = 5.5 V$,	$V_{IN} \le 0.2 V$	$V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.1	0.2				mA
Icc	$V_{CC} = 5.25 \text{ V},$	$V_{IN} \le 0.2 V$	$V_{IN} \ge V_{CC} - 0.2 \text{ V}$					0.1	0.2	IIIA
Aloo	$V_{CC} = 5.5 \text{ V}, \text{ V}_{IN}$	= 3.4 V\$, f ₁ = 0, O	utputs open		0.5	2				mA
∆ICC	V _{CC} = 5.25 V, V _{IN}	$_{\text{N}} = 3.4 \text{ V}, f_{1} = 0, O$	utputs open					0.5	2	IIIA

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.



[‡] Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, $\ensuremath{\text{IOS}}$ tests should be performed last.

 $[\]$ Per TTL-driven input ($V_{IN} = 3.4 \text{ V}$); all other inputs at V_{CC} or GND

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)

DADAMETER		TEST CONDITION	c	CY	54FCT27	73T	CY	74FCT27	73T	LINUT
PARAMETER		TEST CONDITION	MIN	TYP [†]	MAX	MIN	TYP [†]	MAX	UNIT	
loop¶		tputs open, g at 50% duty cycle, M IN ≥ VCC – 0.2 V	R = V _{CC} ,		0.06	0.12				mA/
ICCD¶		utputs open, g at 50% duty cycle, \overline{M} IN \geq V _{CC} $-$ 0.2 V	$\overline{R} = V_{CC}$,					0.06	0.12	MHz
	V _{CC} = 5.5 V,	One bit switching at f ₁ = 2.5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		0.7	1.4				
	$f_0 = 10 \text{ MHz},$	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		1.2	3.4				
	Outputs open, MR = VCC	Eight bits switching at f ₁ = 2.5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$		1.6	3.2				
IC#		at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		3.9	12.2				mA
I IC"	V _{CC} = 5.25 V,	One bit switching at f ₁ = 5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$					0.7	1.4	mA
	$f_0 = 10 \text{ MHz},$	at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$					1.2	3.4	
	Outputs open, MR = V _{CC}	Eight bits switching at f ₁ = 5 MHz	$V_{IN} \le 0.2 \text{ V or}$ $V_{IN} \ge V_{CC} - 0.2 \text{ V}$					1.6	3.2	
		at 50% duty cycle	V _{IN} = 3.4 V or GND					3.9	12.2	
C _i					5	10		5	10	pF
Co					9	12		9	12	pF

[†] Typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

Where:

 $\begin{array}{ll} I_C & = \mbox{Total supply current} \\ I_{CC} & = \mbox{Power-supply current with CMOS input levels} \end{array}$

 ΔI_{CC} = Power-supply current for a TTL high input ($V_{IN} = 3.4 \text{ V}$)

D_H = Duty cycle for TTL inputs high N_T = Number of TTL inputs at D_H

ICCD = Dynamic current caused by an input transition pair (HLH or LHL)

= Clock frequency for registered devices, otherwise zero

= Input signal frequency

= Number of inputs changing at f₁

All currents are in milliamperes and all frequencies are in megahertz.

|| Values for these conditions are examples of the I_{CC} formula.

This parameter is derived for use in total power-supply calculations.

 $^{^{\#}}$ IC = ICC + \triangle ICC \times D_H \times N_T + ICCD ($f_0/2 + f_1 \times N_1$)

CY54FCT273T, CY74FCT273T 8-BIT REGISTERS

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timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

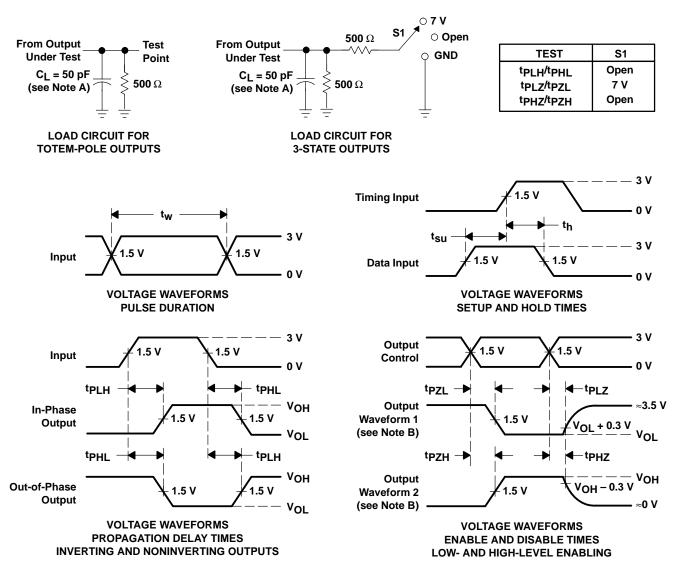
			CY74FCT273T		CY54FCT	273AT	CY74FCT	273AT	CY74FCT	273CT	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
	Pulse duration, high or low	СР	6		6		6		6		no
t _w	Pulse duration, high or low	MR	6		6		6		6		ns
t _{su}	Setup time, high or low	D before CP↑	2		2		2		2		ns
th	Hold time, high or low	D after CP↑	1.5		1.5		1.5		1.5		ns
t _{rec}	Recovery time	MR after CP↑	2		2.5		2		2		ns

switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM	то	CY74FC	T273T	CY54FC	Г273АТ	CY74FC	7273AT	CY74FC	Г273СТ	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	СР	Q	2	13	2	8.3	2	7.2	2	5.8	no
t _{PHL}	CP	Q	2	13	2	8.3	2	7.2	2	5.8	ns
t _{PLH}	MR	Q	2	13	2	8.3	2	7.2	2	6.1	no
t _{PHL}	IVIK	Q	2	13	2	8.3	2	7.2	2	6.1	ns



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9221503M2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9221503M2A CY54FCT 273ATLMB	Samples
5962-9221503MRA	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9221503MR A	Samples
CY54FCT273ATLMB	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9221503M2A CY54FCT 273ATLMB	Samples
CY74FCT273ATQCT	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT273A	Samples
CY74FCT273ATSOC	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT273A	Samples
CY74FCT273ATSOCT	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT273A	Samples
CY74FCT273CTQCT	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT273C	Samples
CY74FCT273CTSOC	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT273C	Samples
CY74FCT273TQCT	ACTIVE	SSOP	DBQ	20	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT273	Samples
CY74FCT273TSOC	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT273	Samples
CY74FCT273TSOCT	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	FCT273	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".



PACKAGE OPTION ADDENDUM

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Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

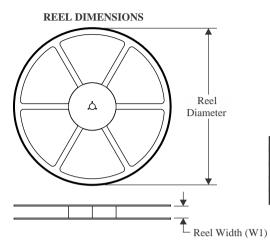
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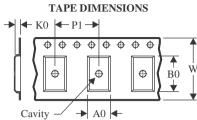
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PACKAGE MATERIALS INFORMATION

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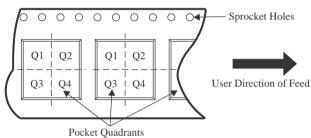
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

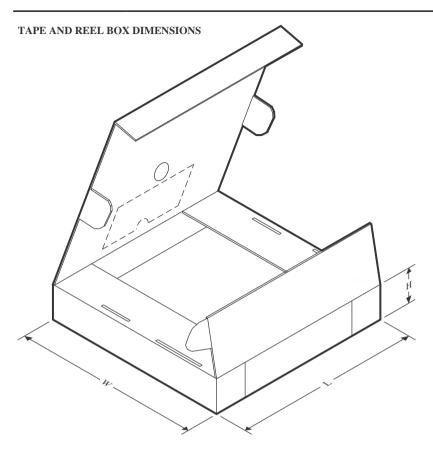


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT273ATQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT273ATSOCT	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CY74FCT273CTQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT273TQCT	SSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT273TSOCT	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1



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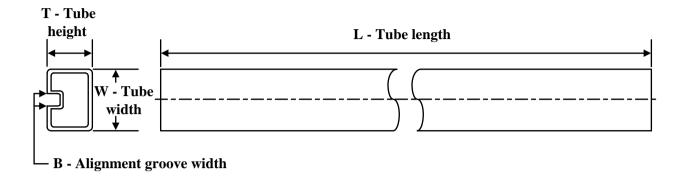
*All dimensions are nominal

7 III GIII I GII GII GII GII GII GII GII							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT273ATQCT	SSOP	DBQ	20	2500	356.0	356.0	35.0
CY74FCT273ATSOCT	SOIC	DW	20	2000	367.0	367.0	45.0
CY74FCT273CTQCT	SSOP	DBQ	20	2500	356.0	356.0	35.0
CY74FCT273TQCT	SSOP	DBQ	20	2500	356.0	356.0	35.0
CY74FCT273TSOCT	SOIC	DW	20	2000	367.0	367.0	45.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9221503M2A	FK	LCCC	20	1	506.98	12.06	2030	NA
CY54FCT273ATLMB	FK	LCCC	20	1	506.98	12.06	2030	NA
CY74FCT273ATSOC	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT273CTSOC	DW	SOIC	20	25	507	12.83	5080	6.6
CY74FCT273TSOC	DW	SOIC	20	25	507	12.83	5080	6.6

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M74HC175B1R M74HC174RM13TR